### INTEGRATED CIRCUITS

# DATA SHEET

For a complete data sheet, please also download:

- The IC04 LOCMOS HE4000B Logic Family Specifications HEF, HEC
- The IC04 LOCMOS HE4000B Logic Package Outlines/Information HEF, HEC

## HEF4520B MSI Dual binary counter

Product specification
File under Integrated Circuits, IC04

January 1995





## **Dual binary counter**

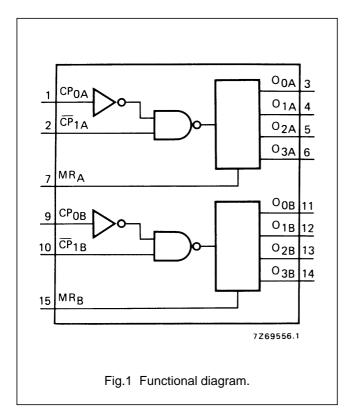
HEF4520B MSI

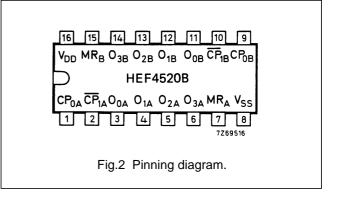
#### **DESCRIPTION**

The HEF4520B is a dual 4-bit internally synchronous binary counter. The counter has an active HIGH clock input (CP $_0$ ) and an active LOW clock input ( $\overline{\text{CP}}_1$ ), buffered outputs from all four bit positions (O $_0$  to O $_3$ ) and an active HIGH overriding asynchronous master reset input (MR). The counter advances on either the LOW to HIGH transition of the CP $_0$  input if  $\overline{\text{CP}}_1$  is HIGH or the HIGH to

LOW transition of the  $\overline{CP}_1$  input if  $CP_0$  is low. Either  $CP_0$  or  $\overline{CP}_1$  may be used as the clock input to the counter and the other clock input may be used as a clock enable input. A HIGH on MR resets the counter ( $O_0$  to  $O_3$  = LOW) independent of  $CP_0$ ,  $\overline{CP}_1$ .

Schmitt-trigger action in the clock input makes the circuit highly tolerant to slower clock rise and fall times.





HEF4520BP(N): 16-lead DIL; plastic

(SOT38-1)

HEF4520BD(F): 16-lead DIL; ceramic (cerdip)

(SOT74)

HEF4520BT(D): 16-lead SO; plastic (SOT109-1)

(SOT109-1)

(): Package Designator North America

#### **PINNING**

 $CP_{0A}$ ,  $CP_{0B}$  clock inputs (L to H triggered)  $\overline{CP}_{1A}$ ,  $\overline{CP}_{1B}$  clock inputs (H to L triggered)

MR<sub>A</sub>, MR<sub>B</sub> master reset inputs

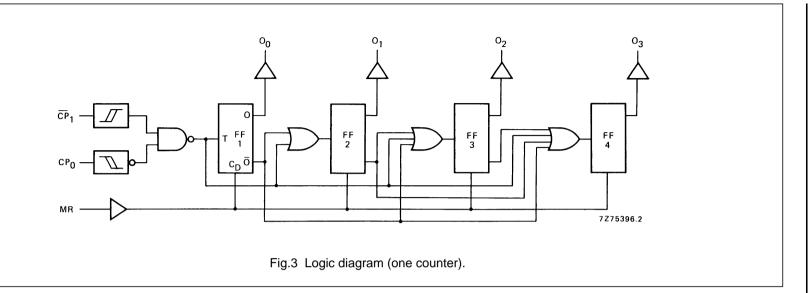
 $O_{0A}$  to  $O_{3A}$  outputs  $O_{0B}$  to  $O_{3B}$  outputs

#### FAMILY DATA, IDD LIMITS category MSI

See Family Specifications

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#### **FUNCTION TABLE**

CP <sub>0</sub>	CP <sub>1</sub>	MR	MODE
_	Н	L	counter advances
L	\ \	L	counter advances
~	X	L	no change
X		L	no change
_	L	L	no change
Н	\ \	L	no change
X	X	Н	$O_0$ to $O_3 = LOW$

#### Notes

1. H = HIGH state (the more positive voltage)

L = LOW state (the less positive voltage)

X = state is immaterial

✓ = positive-going transition

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## Dual binary counter

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#### **AC CHARACTERISTICS**

 $V_{SS}$  = 0 V;  $T_{amb}$  = 25 °C;  $C_L$  = 50 pF; input transition times  $\leq$  20 ns

	V <sub>DD</sub>	SYMBOL	MIN.	TYP.	MAX.		TYPICAL EXTRAPOLATION FORMULA
Propagation delays							
$CP_0$ , $\overline{CP}_1  o O_n$	5			110	220	ns	83 ns + (0,55 ns/pF) C <sub>L</sub>
HIGH to LOW	10	t <sub>PHL</sub>		50	100	ns	39 ns + (0,23 ns/pF) C <sub>L</sub>
	15			40	80	ns	32 ns + (0,16 ns/pF) C <sub>L</sub>
	5			110	220	ns	83 ns + (0,55 ns/pF) C <sub>L</sub>
LOW to HIGH	10	t <sub>PLH</sub>		50	100	ns	39 ns + (0,23 ns/pF) C <sub>L</sub>
	15			40	80	ns	32 ns + (0,16 ns/pF) C <sub>L</sub>
$MR \rightarrow O_n$	5			75	150	ns	48 ns + (0,55 ns/pF) C <sub>L</sub>
HIGH to LOW	10	t <sub>PHL</sub>		35	70	ns	24 ns + (0,23 ns/pF) C <sub>L</sub>
	15			25	50	ns	17 ns + (0,16 ns/pF) C <sub>L</sub>
Output transition							
times	5			60	120	ns	10 ns + (1,0 ns/pF) C <sub>L</sub>
HIGH to LOW	10	t <sub>THL</sub>		30	60	ns	9 ns + (0,42 ns/pF) C <sub>L</sub>
	15			20	40	ns	6 ns + (0,28 ns/pF) C <sub>L</sub>
	5			60	120	ns	10 ns + (1,0 ns/pF) C <sub>L</sub>
LOW to HIGH	10	t <sub>TLH</sub>		30	60	ns	9 ns + (0,42 ns/pF) C <sub>L</sub>
	15			20	40	ns	6 ns + (0,28 ns/pF) C <sub>L</sub>
Minimum CP <sub>0</sub>	5		60	30		ns	
pulse width; LOW	10	t <sub>WCPL</sub>	30	15		ns	
	15		20	10		ns	
Minimum $\overline{CP}_1$	5		60	30		ns	
pulse width; HIGH	10	t <sub>WCPH</sub>	30	15		ns	
	15		20	10		ns	
Minimum MR	5		30	15		ns	
pulse width; HIGH	10	t <sub>WMRH</sub>	20	10		ns	
	15		16	8		ns	see also waveforms
Recovery time	5		50	25		ns	Figs 4 and 5
for MR	10	t <sub>RMR</sub>	30	15		ns	
	15		20	10		ns	
Set-up times	5		50	25		ns	
$CP_0 \rightarrow \overline{CP}_1$	10	t <sub>su</sub>	30	15		ns	
	15		20	10		ns	
	5		50	25		ns	
$\overline{CP}_1 \rightarrow CP_0$	10	t <sub>su</sub>	30	15		ns	
	15		20	10		ns	
Maximum clock	5		8	16		MHz	
pulse frequency	10	f <sub>max</sub>	15	30		MHz	
	15		20	40		MHz	

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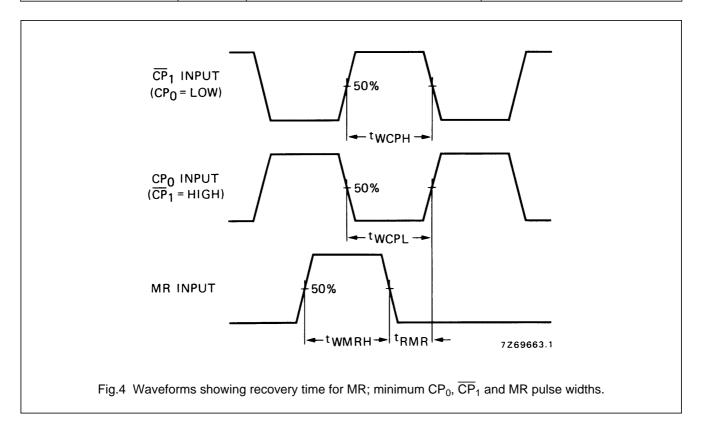
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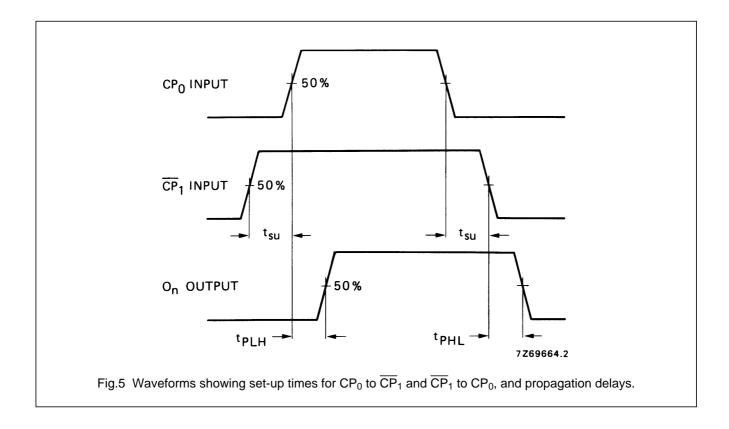
	V <sub>DD</sub>	TYPICAL FORMULA FOR P (μW)	
Dynamic power	5	850 $f_i + \sum (f_o C_L) \times V_{DD}^2$	where
dissipation per	10	$3~800~f_i + \sum (f_o C_L) \times V_{DD}^2$	f <sub>i</sub> = input freq. (MHz)
package (P)	15	10 200 $f_i + \sum (f_o C_L) \times V_{DD}^2$	f <sub>o</sub> = output freq. (MHz)
			C <sub>L</sub> = load capacitance (pF)
			$\sum (f_0C_L) = \text{sum of outputs}$
			V <sub>DD</sub> = supply voltage (V)



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